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#### Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

#### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	264
Number of Logic Elements/Cells	2112
Total RAM Bits	75776
Number of I/O	104
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	132-LFBGA, CSPBGA
Supplier Device Package	132-CSPBGA (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo2-2000ze-2mg132c

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



## Figure 2-4. Slice Diagram



For Slices 0 and 1, memory control signals are generated from Slice 2 as follows:

- WCK is CLK
   WRE is from LSR
- DI[3:2] for Slice 1 and DI[1:0] for Slice 0 data from Slice 2
- WAD [A:D] is a 4-bit address from slice 2 LUT input

 Table 2-2. Slice Signal Descriptions

Function	Туре	Signal Names	Description
Input	Data signal	A0, B0, C0, D0	Inputs to LUT4
Input	Data signal	A1, B1, C1, D1	Inputs to LUT4
Input	Multi-purpose	M0/M1	Multi-purpose input
Input	Control signal	CE	Clock enable
Input	Control signal	LSR	Local set/reset
Input	Control signal	CLK	System clock
Input	Inter-PFU signal	FCIN	Fast carry in <sup>1</sup>
Output	Data signals	F0, F1	LUT4 output register bypass signals
Output	Data signals	Q0, Q1	Register outputs
Output	Data signals	OFX0	Output of a LUT5 MUX
Output	Data signals	OFX1	Output of a LUT6, LUT7, LUT8 <sup>2</sup> MUX depending on the slice
Output	Inter-PFU signal	FCO	Fast carry out <sup>1</sup>

1. See Figure 2-3 for connection details.

2. Requires two PFUs.



## **ROM Mode**

ROM mode uses the LUT logic; hence, slices 0-3 can be used in ROM mode. Preloading is accomplished through the programming interface during PFU configuration.

For more information on the RAM and ROM modes, please refer to TN1201, Memory Usage Guide for MachXO2 Devices.

## Routing

There are many resources provided in the MachXO2 devices to route signals individually or as buses with related control signals. The routing resources consist of switching circuitry, buffers and metal interconnect (routing) segments.

The inter-PFU connections are made with three different types of routing resources: x1 (spans two PFUs), x2 (spans three PFUs) and x6 (spans seven PFUs). The x1, x2, and x6 connections provide fast and efficient connections in the horizontal and vertical directions.

The design tools take the output of the synthesis tool and places and routes the design. Generally, the place and route tool is completely automatic, although an interactive routing editor is available to optimize the design.

## **Clock/Control Distribution Network**

Each MachXO2 device has eight clock inputs (PCLK [T, C] [Banknum]\_[2..0]) – three pins on the left side, two pins each on the bottom and top sides and one pin on the right side. These clock inputs drive the clock nets. These eight inputs can be differential or single-ended and may be used as general purpose I/O if they are not used to drive the clock nets. When using a single ended clock input, only the PCLKT input can drive the clock tree directly.

The MachXO2 architecture has three types of clocking resources: edge clocks, primary clocks and secondary high fanout nets. MachXO2-640U, MachXO2-1200/U and higher density devices have two edge clocks each on the top and bottom edges. Lower density devices have no edge clocks. Edge clocks are used to clock I/O registers and have low injection time and skew. Edge clock inputs are from PLL outputs, primary clock pads, edge clock bridge outputs and CIB sources.

The eight primary clock lines in the primary clock network drive throughout the entire device and can provide clocks for all resources within the device including PFUs, EBRs and PICs. In addition to the primary clock signals, MachXO2 devices also have eight secondary high fanout signals which can be used for global control signals, such as clock enables, synchronous or asynchronous clears, presets, output enables, etc. Internal logic can drive the global clock network for internally-generated global clocks and control signals.

The maximum frequency for the primary clock network is shown in the MachXO2 External Switching Characteristics table.

The primary clock signals for the MachXO2-256 and MachXO2-640 are generated from eight 17:1 muxes The available clock sources include eight I/O sources and 9 routing inputs. Primary clock signals for the MachXO2-640U, MachXO2-1200/U and larger devices are generated from eight 27:1 muxes The available clock sources include eight I/O sources, 11 routing inputs, eight clock divider inputs and up to eight sysCLOCK PLL outputs.



#### Figure 2-9. Memory Core Reset



For further information on the sysMEM EBR block, please refer to TN1201, Memory Usage Guide for MachXO2 Devices.

#### EBR Asynchronous Reset

EBR asynchronous reset or GSR (if used) can only be applied if all clock enables are low for a clock cycle before the reset is applied and released a clock cycle after the reset is released, as shown in Figure 2-10. The GSR input to the EBR is always asynchronous.

#### Figure 2-10. EBR Asynchronous Reset (Including GSR) Timing Diagram

Reset	
Clock	
Clock	

If all clock enables remain enabled, the EBR asynchronous reset or GSR may only be applied and released after the EBR read and write clock inputs are in a steady state condition for a minimum of 1/f<sub>MAX</sub> (EBR clock). The reset release must adhere to the EBR synchronous reset setup time before the next active read or write clock edge.

If an EBR is pre-loaded during configuration, the GSR input must be disabled or the release of the GSR during device wake up must occur before the release of the device I/Os becoming active.

These instructions apply to all EBR RAM, ROM and FIFO implementations. For the EBR FIFO mode, the GSR signal is always enabled and the WE and RE signals act like the clock enable signals in Figure 2-10. The reset timing rules apply to the RPReset input versus the RE input and the RST input versus the WE and RE inputs. Both RST and RPReset are always asynchronous EBR inputs. For more details refer to TN1201, Memory Usage Guide for MachXO2 Devices.

Note that there are no reset restrictions if the EBR synchronous reset is used and the EBR GSR input is disabled.



## Programmable I/O Cells (PIC)

The programmable logic associated with an I/O is called a PIO. The individual PIO are connected to their respective sysIO buffers and pads. On the MachXO2 devices, the PIO cells are assembled into groups of four PIO cells called a Programmable I/O Cell or PIC. The PICs are placed on all four sides of the device.

On all the MachXO2 devices, two adjacent PIOs can be combined to provide a complementary output driver pair.

The MachXO2-640U, MachXO2-1200/U and higher density devices contain enhanced I/O capability. All PIO pairs on these larger devices can implement differential receivers. Half of the PIO pairs on the top edge of these devices can be configured as true LVDS transmit pairs. The PIO pairs on the bottom edge of these higher density devices have on-chip differential termination and also provide PCI support.



## Table 2-11. I/O Support Device by Device

	MachXO2-256, MachXO2-640	MachXO2-640U, MachXO2-1200	MachXO2-1200U MachXO2-2000/U, MachXO2-4000, MachXO2-7000
Number of I/O Banks	4	4	6
		Single-ended (all I/O banks)	Single-ended (all I/O banks)
Tupo of Input Pufforo	Single-ended (all I/O banks)	Differential Receivers (all I/O	Differential Receivers (all I/O
	Differential Receivers (all I/O banks)	Differential input termination (bottom side)	Differential input termination (bottom side)
Turses of Output Duffers	Single-ended buffers with	Single-ended buffers with complementary outputs (all I/O banks)	Single-ended buffers with complementary outputs (all I/O banks)
Types of Output Bullers	complementary outputs (all I/O banks) LVDS outputs (50% on to side)		Differential buffers with true LVDS outputs (50% on top side)
Differential Output Emulation Capability	All I/O banks	All I/O banks	All I/O banks
PCI Clamp Support	No	Clamp on bottom side only	Clamp on bottom side only

## Table 2-12. Supported Input Standards

	VCCIO (Typ.)				
Input Standard	3.3 V	2.5 V	1.8 V	1.5	1.2 V
Single-Ended Interfaces					
LVTTL	✓	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	
LVCMOS33	✓	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	
LVCMOS25	<b>√</b> <sup>2</sup>	✓	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	
LVCMOS18	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	✓	<b>√</b> <sup>2</sup>	
LVCMOS15	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	~	<b>√</b> <sup>2</sup>
LVCMOS12	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	<b>√</b> <sup>2</sup>	✓
PCI <sup>1</sup>	✓				
SSTL18 (Class I, Class II)	✓	✓	✓		
SSTL25 (Class I, Class II)	✓	✓			
HSTL18 (Class I, Class II)	✓	✓	✓		
Differential Interfaces		•			
LVDS	✓	✓			
BLVDS, MVDS, LVPECL, RSDS	✓	✓			
MIPI <sup>3</sup>	✓	✓			
Differential SSTL18 Class I, II	✓	✓	✓		
Differential SSTL25 Class I, II	✓	✓			
Differential HSTL18 Class I, II	✓	~	✓		

1. Bottom banks of MachXO2-640U, MachXO2-1200/U and higher density devices only.

2. Reduced functionality. Refer to TN1202, MachXO2 sysIO Usage Guide for more detail.

3. These interfaces can be emulated with external resistors in all devices.



#### Table 2-13. Supported Output Standards

Output Standard	V <sub>CCIO</sub> (Typ.)
Single-Ended Interfaces	
LVTTL	3.3
LVCMOS33	3.3
LVCMOS25	2.5
LVCMOS18	1.8
LVCMOS15	1.5
LVCMOS12	1.2
LVCMOS33, Open Drain	—
LVCMOS25, Open Drain	—
LVCMOS18, Open Drain	—
LVCMOS15, Open Drain	—
LVCMOS12, Open Drain	—
PCI33	3.3
SSTL25 (Class I)	2.5
SSTL18 (Class I)	1.8
HSTL18(Class I)	1.8
Differential Interfaces	
LVDS <sup>1, 2</sup>	2.5, 3.3
BLVDS, MLVDS, RSDS <sup>2</sup>	2.5
LVPECL <sup>2</sup>	3.3
MIPI <sup>2</sup>	2.5
Differential SSTL18	1.8
Differential SSTL25	2.5
Differential HSTL18	1.8

1. MachXO2-640U, MachXO2-1200/U and larger devices have dedicated LVDS buffers. 2. These interfaces can be emulated with external resistors in all devices.

## sysIO Buffer Banks

The numbers of banks vary between the devices of this family. MachXO2-1200U, MachXO2-2000/U and higher density devices have six I/O banks (one bank on the top, right and bottom side and three banks on the left side). The MachXO2-1200 and lower density devices have four banks (one bank per side). Figures 2-18 and 2-19 show the sysIO banks and their associated supplies for all devices.



# MachXO2 Family Data Sheet DC and Switching Characteristics

#### March 2017

#### Data Sheet DS1035

## Absolute Maximum Ratings<sup>1, 2, 3</sup>

	MachXO2 ZE/HE (1.2 V)	MachXO2 HC (2.5 V / 3.3 V)
Supply Voltage V <sub>CC</sub>	–0.5 V to 1.32 V	0.5 V to 3.75 V
Output Supply Voltage V <sub>CCIO</sub>	–0.5 V to 3.75 V	0.5 V to 3.75 V
I/O Tri-state Voltage Applied <sup>4, 5</sup>	–0.5 V to 3.75 V	0.5 V to 3.75 V
Dedicated Input Voltage Applied <sup>4</sup>	–0.5 V to 3.75 V	0.5 V to 3.75 V
Storage Temperature (Ambient)	–55 °C to 125 °C	–55 °C to 125 °C
Junction Temperature $(T_1)$	–40 °C to 125 °C	–40 °C to 125 °C

1. Stress above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

2. Compliance with the Lattice Thermal Management document is required.

3. All voltages referenced to GND.

4. Overshoot and undershoot of -2 V to (V<sub>IHMAX</sub> + 2) volts is permitted for a duration of <20 ns.

5. The dual function  $I^2C$  pins SCL and SDA are limited to -0.25 V to 3.75 V or to -0.3 V with a duration of <20 ns.

## **Recommended Operating Conditions**<sup>1</sup>

Symbol	Parameter	Min.	Max.	Units
V = = <sup>1</sup>	Core Supply Voltage for 1.2 V Devices	1.14	1.26	V
VCC	Core Supply Voltage for 2.5 V / 3.3 V Devices	2.375	3.6	V
V <sub>CCIO</sub> <sup>1, 2, 3</sup>	I/O Driver Supply Voltage	1.14	3.6	V
t <sub>JCOM</sub>	Junction Temperature Commercial Operation	0	85	°C
t <sub>JIND</sub>	Junction Temperature Industrial Operation	-40	100	°C

1. Like power supplies must be tied together. For example, if  $V_{CCIO}$  and  $V_{CC}$  are both the same voltage, they must also be the same supply.

2. See recommended voltages by I/O standard in subsequent table.

3. V<sub>CCIO</sub> pins of unused I/O banks should be connected to the V<sub>CC</sub> power supply on boards.

## Power Supply Ramp Rates<sup>1</sup>

Symbol	Parameter	Min.	Тур.	Max.	Units
t <sub>RAMP</sub>	Power supply ramp rates for all power supplies.	0.01		100	V/ms

1. Assumes monotonic ramp rates.

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## **DC Electrical Characteristics**

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
		Clamp OFF and $V_{CCIO} < V_{IN} < V_{IH}$ (MAX)			+175	μΑ
		Clamp OFF and $V_{IN} = V_{CCIO}$	-10	—	10	μΑ
I <sub>II</sub> , I <sub>IH</sub> <sup>1, 4</sup>	Input or I/O Leakage	Clamp OFF and V <sub>CCIO</sub> –0.97 V < V <sub>IN</sub> < V <sub>CCIO</sub>	-175	—	—	μA
		Clamp OFF and 0 V < $V_{IN}$ < $V_{CCIO}$ –0.97 V			10	μΑ
		Clamp OFF and V <sub>IN</sub> = GND			10	μA
		Clamp ON and 0 V < V <sub>IN</sub> < V <sub>CCIO</sub>			10	μA
I <sub>PU</sub>	I/O Active Pull-up Current	0 < V <sub>IN</sub> < 0.7 V <sub>CCIO</sub>	-30		-309	μΑ
I <sub>PD</sub>	I/O Active Pull-down Current	$V_{IL}$ (MAX) < $V_{IN}$ < $V_{CCIO}$	30	_	305	μA
I <sub>BHLS</sub>	Bus Hold Low sustaining current	$V_{IN} = V_{IL} (MAX)$	30	—	—	μΑ
I <sub>BHHS</sub>	Bus Hold High sustaining current	$V_{IN} = 0.7 V_{CCIO}$	-30	_	_	μΑ
I <sub>BHLO</sub>	Bus Hold Low Overdrive current	$0 \leq V_{IN} \leq V_{CCIO}$	—	_	305	μΑ
I <sub>BHHO</sub>	Bus Hold High Overdrive current	$0 \leq V_{IN} \leq V_{CCIO}$	—	_	-309	μΑ
V <sub>BHT</sub> <sup>3</sup>	Bus Hold Trip Points		V <sub>IL</sub> (MAX)	_	V <sub>IH</sub> (MIN)	v
C1	I/O Capacitance <sup>2</sup>	$V_{CCIO} = 3.3 V, 2.5 V, 1.8 V, 1.5 V, 1.2 V, V_{CC} = Typ., V_{IO} = 0 \text{ to } V_{IH} \text{ (MAX)}$	3	5	9	pF
C2	Dedicated Input Capacitance <sup>2</sup>	$V_{CCIO} = 3.3 \text{ V}, 2.5 \text{ V}, 1.8 \text{ V}, 1.5 \text{ V}, 1.2 \text{ V}, V_{CC} = Typ., V_{IO} = 0 \text{ to } V_{IH} \text{ (MAX)}$	3	5.5	7	pF
		V <sub>CCIO</sub> = 3.3 V, Hysteresis = Large		450		mV
		V <sub>CCIO</sub> = 2.5 V, Hysteresis = Large		250		mV
		V <sub>CCIO</sub> = 1.8 V, Hysteresis = Large		125		mV
M	Hysteresis for Schmitt	V <sub>CCIO</sub> = 1.5 V, Hysteresis = Large		100		mV
V HYST	Trigger Inputs⁵	V <sub>CCIO</sub> = 3.3 V, Hysteresis = Small		250		mV
		V <sub>CCIO</sub> = 2.5 V, Hysteresis = Small		150		mV
		V <sub>CCIO</sub> = 1.8 V, Hysteresis = Small		60		mV
		V <sub>CCIO</sub> = 1.5 V, Hysteresis = Small	_	40	_	mV

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tri-stated. It is not measured with the output driver active. Bus maintenance circuits are disabled.

2. T<sub>A</sub> 25 °C, f = 1.0 MHz.

3. Please refer to  $V_{IL}$  and  $V_{IH}$  in the sysIO Single-Ended DC Electrical Characteristics table of this document.

4. When V<sub>IH</sub> is higher than V<sub>CCIO</sub>, a transient current typically of 30 ns in duration or less with a peak current of 6 mA can occur on the high-to-low transition. For true LVDS output pins in MachXO2-640U, MachXO2-1200/U and larger devices, V<sub>IH</sub> must be less than or equal to V<sub>CCIO</sub>.

5. With bus keeper circuit turned on. For more details, refer to TN1202, MachXO2 sysIO Usage Guide.



## LVPECL

The MachXO2 family supports the differential LVPECL standard through emulation. This output standard is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs on all the devices. The LVPECL input standard is supported by the LVDS differential input buffer. The scheme shown in Differential LVPECL is one possible solution for point-to-point signals.

## Figure 3-3. Differential LVPECL



## Table 3-3. LVPECL DC Conditions<sup>1</sup>

Symbol	Description	Nominal	Units
Z <sub>OUT</sub>	Output impedance	20	Ohms
R <sub>S</sub>	Driver series resistor	93	Ohms
R <sub>P</sub>	Driver parallel resistor	196	Ohms
R <sub>T</sub>	Receiver termination	100	Ohms
V <sub>OH</sub>	Output high voltage	2.05	V
V <sub>OL</sub>	Output low voltage	1.25	V
V <sub>OD</sub>	Output differential voltage	0.80	V
V <sub>CM</sub>	Output common mode voltage	1.65	V
Z <sub>BACK</sub>	Back impedance	100.5	Ohms
I <sub>DC</sub>	DC output current	12.11	mA

#### **Over Recommended Operating Conditions**

1. For input buffer, see LVDS table.

For further information on LVPECL, BLVDS and other differential interfaces please see details of additional technical documentation at the end of the data sheet.



## Typical Building Block Function Performance – HC/HE Devices<sup>1</sup>

## Pin-to-Pin Performance (LVCMOS25 12 mA Drive)

Function	-6 Timing	Units
Basic Functions		
16-bit decoder	8.9	ns
4:1 MUX	7.5	ns
16:1 MUX	8.3	ns

## **Register-to-Register Performance**

Function	-6 Timing	Units
Basic Functions		·
16:1 MUX	412	MHz
16-bit adder	297	MHz
16-bit counter	324	MHz
64-bit counter	161	MHz
Embedded Memory Functions	·	
1024x9 True-Dual Port RAM (Write Through or Normal, EBR output registers)	183	MHz
Distributed Memory Functions	·	·
16x4 Pseudo-Dual Port RAM (one PFU)	500	MHz

 The above timing numbers are generated using the Diamond design tool. Exact performance may vary with device and tool version. The tool uses internal parameters that have been characterized but are not tested on every device. Commercial timing numbers are shown at 85 °C and 1.14 V. Other operating conditions, including industrial, can be extracted from the Diamond software.





			-6		-5		-4		
Parameter	Description	Device	Min.	Max.	Min.	Max.	Min.	Max.	Units
		MachXO2-256HC-HE	1.42	_	1.59	_	1.96	_	ns
		MachXO2-640HC-HE	1.41	_	1.58	_	1.96	_	ns
	Clock to Data Setup – PIO	MachXO2-1200HC-HE	1.63	_	1.79	_	2.17	_	ns
<sup>I</sup> SU_DEL	Delav	MachXO2-2000HC-HE	1.61	_	1.76	_	2.13	_	ns
		MachXO2-4000HC-HE	1.66	_	1.81	_	2.19	_	ns
		MachXO2-7000HC-HE	1.53	_	1.67		2.03		ns
		MachXO2-256HC-HE	-0.24	_	-0.24		-0.24		ns
		MachXO2-640HC-HE	-0.23	_	-0.23	_	-0.23	_	ns
+	Clock to Data Hold – PIO Input	MachXO2-1200HC-HE	-0.24	_	-0.24	_	-0.24	_	ns
'H_DEL	Register with Input Data Delay	MachXO2-2000HC-HE	-0.23	_	-0.23		-0.23		ns
		MachXO2-4000HC-HE	-0.25	_	-0.25	_	-0.25	_	ns
		MachXO2-7000HC-HE	-0.21		-0.21		-0.21		ns
f <sub>MAX_IO</sub>	Clock Frequency of I/O and PFU Register	All MachXO2 devices		388	_	323	_	269	MHz
General I/O	Pin Parameters (Using Edge C	lock without PLL)							
		MachXO2-1200HC-HE	_	7.53	—	7.76	—	8.10	ns
	Clock to Output – PIO Output	MachXO2-2000HC-HE		7.53	—	7.76	—	8.10	ns
<sup>I</sup> COE	Register	MachXO2-4000HC-HE		7.45	—	7.68	—	8.00	ns
		MachXO2-7000HC-HE	_	7.53	—	7.76	—	8.10	ns
	Clock to Data Setup – PIO Input Register	MachXO2-1200HC-HE	-0.19	_	-0.19	_	-0.19	_	ns
		MachXO2-2000HC-HE	-0.19		-0.19	_	-0.19		ns
ISUE		MachXO2-4000HC-HE	-0.16		-0.16	_	-0.16		ns
		MachXO2-7000HC-HE	-0.19	_	-0.19	_	-0.19	_	ns
		MachXO2-1200HC-HE	1.97	_	2.24	_	2.52	_	ns
	Clock to Data Hold – PIO Input	MachXO2-2000HC-HE	1.97		2.24		2.52		ns
ЧЕ	Register	MachXO2-4000HC-HE	1.89	_	2.16	_	2.43	_	ns
		MachXO2-7000HC-HE	1.97		2.24		2.52		ns
		MachXO2-1200HC-HE	1.56	_	1.69	_	2.05	_	ns
	Clock to Data Setup – PIO	MachXO2-2000HC-HE	1.56	_	1.69	_	2.05	_	ns
<sup>I</sup> SU_DELE	Delav	MachXO2-4000HC-HE	1.74	_	1.88	_	2.25	_	ns
		MachXO2-7000HC-HE	1.66	_	1.81	_	2.17	_	ns
		MachXO2-1200HC-HE	-0.23	_	-0.23	_	-0.23		ns
	Clock to Data Hold – PIO Input	MachXO2-2000HC-HE	-0.23	_	-0.23	_	-0.23	_	ns
<sup>I</sup> H_DELE	Register with Input Data Delay	MachXO2-4000HC-HE	-0.34	_	-0.34	_	-0.34	_	ns
		MachXO2-7000HC-HE	-0.29	_	-0.29	_	-0.29	_	ns
General I/O	Pin Parameters (Using Primary	y Clock with PLL)							
		MachXO2-1200HC-HE	_	5.97	—	6.00	—	6.13	ns
	Clock to Output – PIO Output	MachXO2-2000HC-HE	_	5.98	—	6.01	—	6.14	ns
<sup>I</sup> COPLL	Register	MachXO2-4000HC-HE	_	5.99	—	6.02	—	6.16	ns
		MachXO2-7000HC-HE		6.02	—	6.06	—	6.20	ns
		MachXO2-1200HC-HE	0.36	—	0.36	—	0.65	—	ns
	Clock to Data Setup – PIO	MachXO2-2000HC-HE	0.36	—	0.36	—	0.63	—	ns
ISUPLL	Input Register	MachXO2-4000HC-HE	0.35	_	0.35	_	0.62	_	ns
		MachXO2-7000HC-HE	0.34	—	0.34	—	0.59	—	ns
J	1		t	1	I	1	I	1	







#### Figure 3-6. Receiver RX.CLK.Centered Waveforms



## Figure 3-7. Transmitter TX.CLK.Aligned Waveforms



Figure 3-8. Transmitter TX.CLK.Centered and MEM DDR Output Waveforms











# MachXO2 Family Data Sheet Pinout Information

March 2017

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## **Signal Descriptions**

Signal Name	I/O	Descriptions				
General Purpose						
		[Edge] indicates the edge of the device on which the pad is located. Valid edge designations are L (Left), B (Bottom), R (Right), T (Top).				
		[Row/Column Number] indicates the PFU row or the column of the device on which the PIO Group exists. When Edge is T (Top) or (Bottom), only need to specify Row Number. When Edge is L (Left) or R (Right), only need to specify Column Number.				
		[A/B/C/D] indicates the PIO within the group to which the pad is connected.				
P[Edge] [Row/Column Number]_[A/B/C/D]	I/O	Some of these user-programmable pins are shared with special function pins. When not used as special function pins, these pins can be programmed as I/Os for user logic.				
		During configuration of the user-programmable I/Os, the user has an option to tri-state the /Os and enable an internal pull-up, pull-down or buskeeper resistor. This option also applies o unused pins (or those not bonded to a package pin). The default during configuration is for user-programmable I/Os to be tri-stated with an internal pull-down resistor enabled. When the device is erased, I/Os will be tri-stated with an internal pull-down resistor enabled. Some pins, such as PROGRAMN and JTAG pins, default to tri-stated I/Os with pull-up resistors enabled when the device is erased.				
NC	—	No connect.				
GND	_	GND – Ground. Dedicated pins. It is recommended that all GNDs are tied together. For QFN 48 package, the exposed die pad is the device ground.				
VCC	_	$V_{CC}$ – The power supply pins for core logic. Dedicated pins. It is recommended that all VCCs are tied to the same supply.				
VCCIOx	_	VCCIO – The power supply pins for I/O Bank x. Dedicated pins. It is recommended that all VCCIOs located in the same bank are tied to the same supply.				
PLL and Clock Functi	ons (Us	ed as user-programmable I/O pins when not used for PLL or clock pins)				
[LOC]_GPLL[T, C]_IN	_	Reference Clock (PLL) input pads: [LOC] indicates location. Valid designations are L (Left PLL) and R (Right PLL). T = true and C = complement.				
[LOC]_GPLL[T, C]_FB	—	Optional Feedback (PLL) input pads: [LOC] indicates location. Valid designations are L (Left PLL) and R (Right PLL). T = true and C = complement.				
PCLK [n]_[2:0]		Primary Clock pads. One to three clock pads per side.				
Test and Programming	<b>g</b> (Dual t	function pins used for test access port and during sysCONFIG™)				
TMS	I	Test Mode Select input pin, used to control the 1149.1 state machine.				
ТСК	I	Test Clock input pin, used to clock the 1149.1 state machine.				
TDI	I	Test Data input pin, used to load data into the device using an 1149.1 state machine.				
TDO	0	Output pin – Test Data output pin used to shift data out of the device using 1149.1.				
		Optionally controls behavior of TDI, TDO, TMS, TCK. If the device is configured to use the JTAG pins (TDI, TDO, TMS, TCK) as general purpose I/O, then:				
JTAGENB	I	If JTAGENB is low: TDI, TDO, TMS and TCK can function a general purpose I/O.				
		If JTAGENB is high: TDI, TDO, TMS and TCK function as JTAG pins.				
		For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.				
Configuration (Dual fu	nction p	ins used during sysCONFIG)				
PROGRAMN	I	Initiates configuration sequence when asserted low. During configuration, or when reserved as PROGRAMN in user mode, this pin always has an active pull-up.				

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		MachXO2-1200U				
	100 TQFP	132 csBGA	144 TQFP	25 WLCSP	32 QFN <sup>1</sup>	256 ftBGA
General Purpose I/O per Bank						
Bank 0	18	25	27	11	9	50
Bank 1	21	26	26	0	2	52
Bank 2	20	28	28	7	9	52
Bank 3	20	25	26	0	2	16
Bank 4	0	0	0	0	0	16
Bank 5	0	0	0	0	0	20
Total General Purpose Single Ended I/O	79	104	107	18	22	206
Differential I/O per Bank						
Bank 0	9	13	14	5	4	25
Bank 1	10	13	13	0	1	26
Bank 2	10	14	14	2	4	26
Bank 3	10	12	13	0	1	8
Bank 4	0	0	0	0	0	8
Bank 5	0	0	0	0	0	10
Total General Purpose Differential I/O	39	52	54	7	10	103
Dual Function I/O	31	33	33	18	22	33
High-speed Differential I/O						1
Bank 0	4	7	7	0	0	14
Gearboxes						1
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	4	7	7	0	0	14
Number of 7:1 or 8:1 Input Gearbox Avail- able (Bank 2)	5	7	7	0	2	14
DQS Groups						
Bank 1	1	2	2	0	0	2
VCCIO Pins	1	1				1
Bank 0	2	3	3	1	2	4
Bank 1	2	3	3	0	1	4
Bank 2	2	3	3	1	2	4
Bank 3	3	3	3	0	1	1
Bank 4	0	0	0	0	0	2
Bank 5	0	0	0	0	0	1
	1	1				1
VCC	2	4	4	2	2	8
GND	8	10	12	2	2	24
NC	1	1	8	0	0	1
Reserved for Configuration	1	1	1	1	1	1
Total Count of Bonded Pins	100	132	144	25	32	256

1. Lattice recommends soldering the central thermal pad onto the top PCB ground for improved thermal resistance.



## MachXO2 Family Data Sheet Ordering Information

March 2017

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## MachXO2 Part Number Description



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Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-4000HE-6BG332C	4320	1.2 V	-6	Halogen-Free caBGA	332	COM
LCMXO2-4000HE-4FG484C	4320	1.2 V	-4	Halogen-Free fpBGA	484	COM
LCMXO2-4000HE-5FG484C	4320	1.2 V	-5	Halogen-Free fpBGA	484	COM
LCMXO2-4000HE-6FG484C	4320	1.2 V	-6	Halogen-Free fpBGA	484	COM

Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-7000HE-4TG144C	6864	1.2 V	-4	Halogen-Free TQFP	144	COM
LCMXO2-7000HE-5TG144C	6864	1.2 V	-5	Halogen-Free TQFP	144	COM
LCMXO2-7000HE-6TG144C	6864	1.2 V	-6	Halogen-Free TQFP	144	COM
LCMXO2-7000HE-4BG256C	6864	1.2 V	-4	Halogen-Free caBGA	256	COM
LCMXO2-7000HE-5BG256C	6864	1.2 V	-5	Halogen-Free caBGA	256	COM
LCMXO2-7000HE-6BG256C	6864	1.2 V	-6	Halogen-Free caBGA	256	COM
LCMXO2-7000HE-4FTG256C	6864	1.2 V	-4	Halogen-Free ftBGA	256	COM
LCMXO2-7000HE-5FTG256C	6864	1.2 V	-5	Halogen-Free ftBGA	256	COM
LCMXO2-7000HE-6FTG256C	6864	1.2 V	-6	Halogen-Free ftBGA	256	COM
LCMXO2-7000HE-4BG332C	6864	1.2 V	-4	Halogen-Free caBGA	332	COM
LCMXO2-7000HE-5BG332C	6864	1.2 V	-5	Halogen-Free caBGA	332	COM
LCMXO2-7000HE-6BG332C	6864	1.2 V	-6	Halogen-Free caBGA	332	COM
LCMXO2-7000HE-4FG484C	6864	1.2 V	-4	Halogen-Free fpBGA	484	COM
LCMXO2-7000HE-5FG484C	6864	1.2 V	-5	Halogen-Free fpBGA	484	COM
LCMXO2-7000HE-6FG484C	6864	1.2 V	-6	Halogen-Free fpBGA	484	COM



Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-1200ZE-1TG100IR11	1280	1.2 V	-1	Halogen-Free TQFP	100	IND
LCMXO2-1200ZE-2TG100IR11	1280	1.2 V	-2	Halogen-Free TQFP	100	IND
LCMXO2-1200ZE-3TG100IR11	1280	1.2 V	-3	Halogen-Free TQFP	100	IND
LCMXO2-1200ZE-1MG132IR1 <sup>1</sup>	1280	1.2 V	-1	Halogen-Free csBGA	132	IND
LCMXO2-1200ZE-2MG132IR1 <sup>1</sup>	1280	1.2 V	-2	Halogen-Free csBGA	132	IND
LCMXO2-1200ZE-3MG132IR11	1280	1.2 V	-3	Halogen-Free csBGA	132	IND
LCMXO2-1200ZE-1TG144IR11	1280	1.2 V	-1	Halogen-Free TQFP	144	IND
LCMXO2-1200ZE-2TG144IR11	1280	1.2 V	-2	Halogen-Free TQFP	144	IND
LCMXO2-1200ZE-3TG144IR11	1280	1.2 V	-3	Halogen-Free TQFP	144	IND

1. Specifications for the "LCMXO2-1200ZE-speed package IR1" are the same as the "LCMXO2-1200ZE-speed package I" devices respectively, except as specified in the R1 Device Specifications section of this data sheet.



Date	Version	Section	Change Summary			
May 2016	3.2	All	Moved designation for 84 QFN package information from 'Advanced' to 'Final'.			
		Introduction	Updated the Features section. Revised Table 1-1, MachXO2 Family Selection Guide. — Added 'Advanced' 48 QFN package. — Revised footnote 6. — Added footnote 9.			
		DC and Switching Characteristics	Updated the MachXO2 External Switching Characteristics – HC/HE Devices section. Added footnote 12.			
			Updated the MachXO2 External Switching Characteristics – ZE Devices section. Added footnote 12.			
		Pinout Information	Updated the Signal Descriptions section. Added information on GND signal.			
			Updated the Pinout Information Summary section. — Added 'Advanced' MachXO2-256 48 QFN values. — Added 'Advanced' MachXO2-640 48 QFN values. — Added footnote to GND. — Added footnotes 2 and 3.			
	Orde	Ordering Information	Updated the MachXO2 Part Number Description section. Added 'Advanced' SG48 package and revised footnote.			
			Updated the Ordering Information section. — Added part numbers for 'Advanced' QFN 48 package.			
March 2016 3.1	3.1	Introduction	Updated the Features section. Revised Table 1-1, MachXO2 Family Selection Guide. — Added 32 QFN value for XO2-1200. — Added 84 QFN (7 mm x 7 mm, 0.5 mm) package. — Modified package name to 100-pin TQFP. — Modified package name to 144-pin TQFP. — Added footnote.			
		Architecture	Updated the Typical I/O Behavior During Power-up section. Removed reference to TN1202.			
		DC and Switching Characteristics	Updated the sysCONFIG Port Timing Specifications section. Revised t <sub>DPPDONE</sub> and t <sub>DPPINIT</sub> Max. values per PCN 03A-16, released March 2016.			
		Pinout Information	Updated the Pinout Information Summary section. — Added MachXO2-1200 32 QFN values. — Added 'Advanced' MachXO2-4000 84 QFN values.			
		Ordering Information	Updated the MachXO2 Part Number Description section. Added 'Advanced' QN84 package and footnote.			
			Updated the Ordering Information section. — Added part numbers for 1280 LUTs QFN 32 package. — Added part numbers for 4320 LUTs QFN 84 package.			
March 2015	3.0	Introduction	Updated the Features section. Revised Table 1-1, MachXO2 Family Selection Guide. — Changed 64-ball ucBGA dimension.			
		Architecture	Updated the Device Configuration section. Added JTAGENB to TAP dual purpose pins.			



Date	Version	Section	Change Summary			
January 2013	02.0	Introduction	Updated the total number IOs to include JTAGENB.			
		Architecture	Supported Output Standards table – Added 3.3 $\rm V_{\rm CCIO}$ (Typ.) to LVDS row.			
			Changed SRAM CRC Error Detection to Soft Error Detection.			
		DC and Switching Characteristics	Power Supply Ramp Rates table – Updated Units column for t <sub>RAMP</sub> symbol.			
			Added new Maximum sysIO Buffer Performance table.			
			sysCLOCK PLL Timing table – Updated Min. column values for $f_{IN}$ ,			
			$f_{OUT},f_{OUT2}$ and $f_{PFD}$ parameters. Added $t_{SPO}$ parameter. Updated footnote 6.			
			MachXO2 Oscillator Output Frequency table – Updated symbol name for t <sub>STABLEOSC</sub> .			
			DC Electrical Characteristics table – Updated conditions for ${\rm I}_{\rm IL,}~{\rm I}_{\rm IH}$ symbols.			
			Corrected parameters tDQVBS and tDQVAS			
			Corrected MachXO2 ZE parameters tDVADQ and tDVEDQ			
		Pinout Information	Included the MachXO2-4000HE 184 csBGA package.			
		Ordering Information	Updated part number.			
April 2012	01.9	Architecture	Removed references to TN1200.			
		Ordering Information	Updated the Device Status portion of the MachXO2 Part Number Description to include the 50 parts per reel for the WLCSP package.			
			Added new part number and footnote 2 for LCMXO2-1200ZE- 1UWG25ITR50.			
			Updated footnote 1 for LCMXO2-1200ZE-1UWG25ITR.			
		Supplemental Information	Removed references to TN1200.			
March 2012	01.8	Introduction	Added 32 QFN packaging information to Features bullets and MachXO2 Family Selection Guide table.			
		DC and Switching Characteristics	Changed 'STANDBY' to 'USERSTDBY' in Standby Mode timing dia- gram.			
		Pinout Information	Removed footnote from Pin Information Summary tables.			
			Added 32 QFN package to Pin Information Summary table.			
		Ordering Information	Updated Part Number Description and Ordering Information tables for 32 QFN package.			
			Updated topside mark diagram in the Ordering Information section.			